

SANYO	No.2854	2SC4423
		NPN Triple Diffused Planar Silicon Transistor
Switching Regulator Applications		

Features

- High breakdown voltage, high reliability
- Fast switching speed (t_f : 0.1 μ s typ)
- Wide ASO
- Adoption of MBIT process
- Micaless package facilitating easy mounting

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

			unit
Collector-to-Base Voltage	V_{CB0}	500	V
Collector-to-Emitter Voltage	V_{CEO}	400	V
Emitter-to-Base Voltage	V_{EBO}	7	V
Collector Current	I_C	12	A
Peak Collector Current	i_{cp}	25	A
Base Current	I_B	4	A
Collector Dissipation	P_C	3	W
		$T_C = 25^\circ\text{C}$	
Junction Temperature	T_j	55	W
Storage Temperature	T_{stg}	150	$^\circ\text{C}$
		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

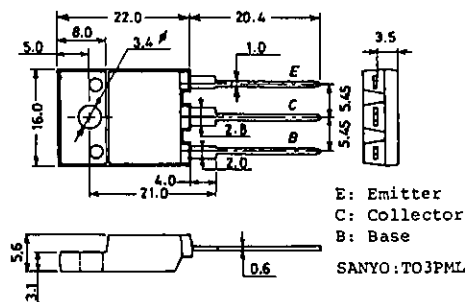
			min	typ	max	unit
Collector Cutoff Current	I_{CBO}	$V_{CB} = 400\text{V}, I_E = 0$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 5\text{V}, I_C = 0$			10	μA
DC Current Gain	$h_{FE(1)*}$	$V_{CE} = 5\text{V}, I_C = 1.6\text{A}$	15		50	
	$h_{FE(2)}$	$V_{CE} = 5\text{V}, I_C = 8\text{A}$	10			
	$h_{FE(3)}$	$V_{CE} = 5\text{V}, I_C = 10\text{mA}$	10			
C-E Saturation Voltage	$V_{CE(sat)}$	$I_C = 8\text{A}, I_B = 1.6\text{A}$			0.8	V
B-E Saturation Voltage	$V_{BE(sat)}$	$I_C = 8\text{A}, I_B = 1.6\text{A}$			1.5	V
Gain-Bandwidth Product	f_T	$V_{CE} = 10\text{V}, I_C = 1.6\text{A}$		20		MHz
Output Capacitance	c_{ob}	$V_{CB} = 10\text{V}, f = 1\text{MHz}$		160		pF
C-B Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 1\text{mA}, I_E = 0$	500			V
C-E Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 5\text{mA}, R_{BE} = \infty$	400			V
E-B Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 1\text{mA}, I_C = 0$	7			V
C-E Sustain Voltage	$V_{CEX(sus)}$	$I_C = 6\text{A}, I_{B1} = 0.6\text{A}$ $I_{B2} = -2.4\text{A}, L = 500\mu\text{H}, \text{clamped}$	400			V

Continued on next page.

*: The $h_{FE(1)}$ of the 2SC4423 is classified as follows. When specifying the $h_{FE(1)}$ rank, specify two ranks or more in principle.

15	L	30	20	M	40	30	N	50
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Package Dimensions 2039
(unit: mm)

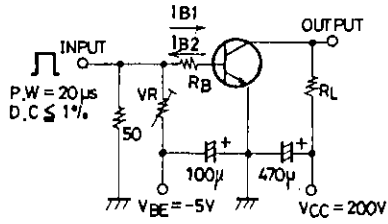


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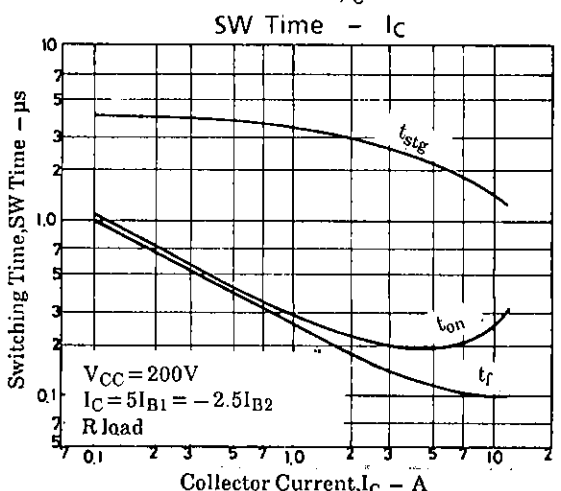
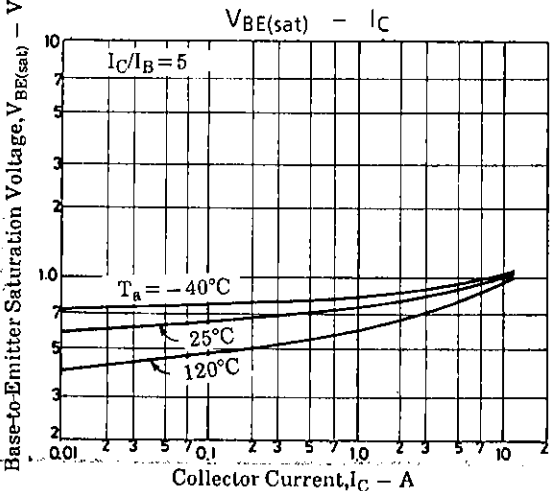
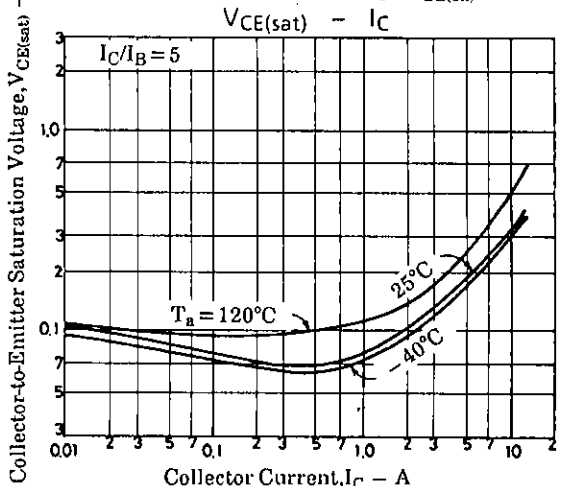
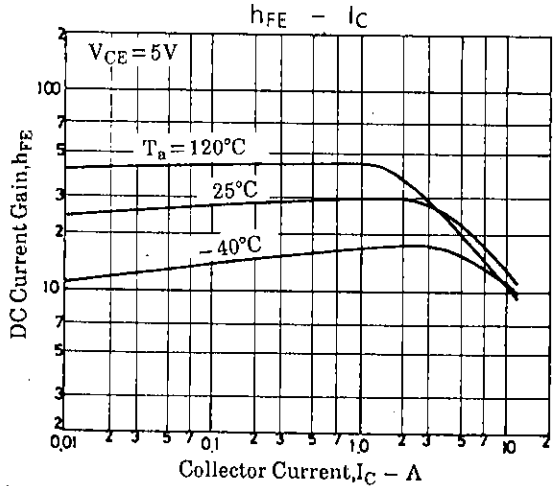
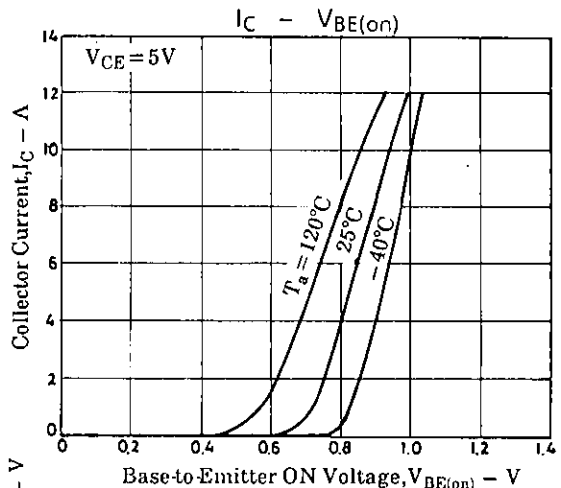
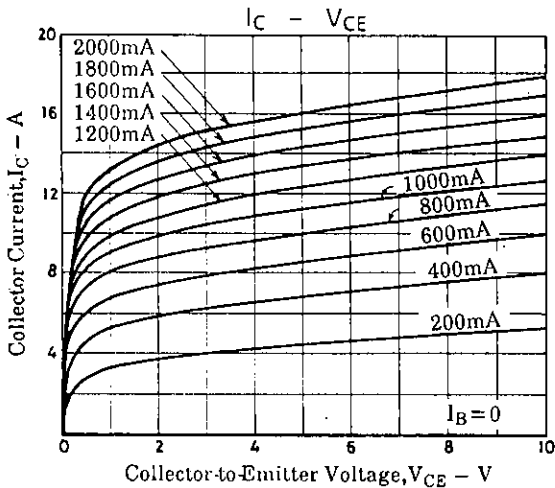
		min	typ	max	unit
Turn-on Time	t_{on}			0.5	μs
Storage Time	t_{stg}			2.5	μs
Fall Time	t_f			0.3	μs

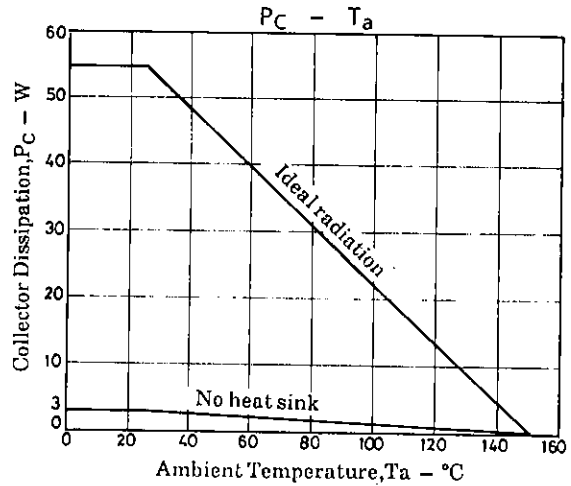
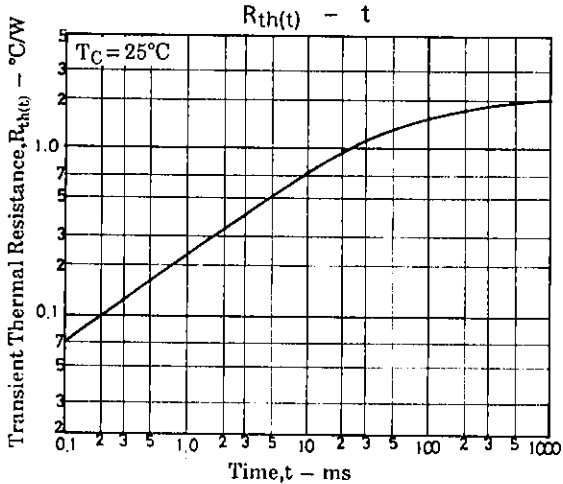
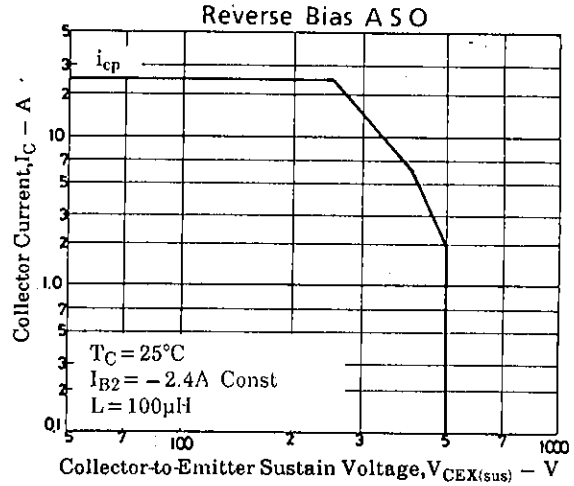
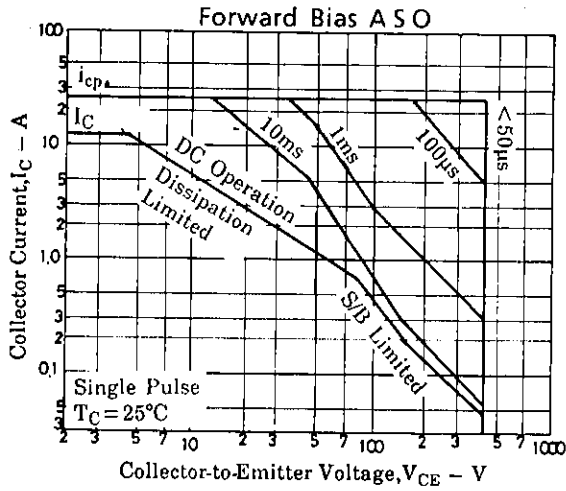
$I_C = 10A, I_{B1} = 2A$
 $I_{B2} = -4A, R_L = 20\Omega$
 $V_{CC} = 200V$

Switching Time Test Circuit



Unit (Resistance : Ω , Capacitance : F)





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